

Product Summary

BV _{DSS}	R _{DS(ON)}	I _D T _A = +25°C
60V	2Ω @ V _{GS} = 10V	0.71A

Description and Applications

This MOSFET is designed to minimize the on-state resistance and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- DC-DC Converters
- Solenoids / Relay Driver for Automotive

Features and Benefits

- V_{(BR)DSS} > 60V
- R_{DS(ON)} ≤ 2Ω @ V_{GS} = 10V
- Maximum Continuous Drain Current I_D = 0.71A
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](#) or your local Diodes representative.**
<https://www.diodes.com/quality/product-definitions/>

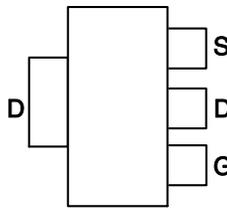
Mechanical Data

- Package: SOT223
- Package Material: Molded Plastic, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Annealed over Copper Leadframe. Ⓔ3
- Solderable per MIL-STD-202, Method 208
- Weight: 0.112 grams (Approximate)

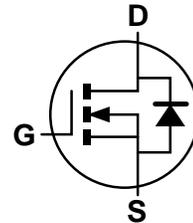
SOT223 (Type DN)



Top View



Pin Out - Top



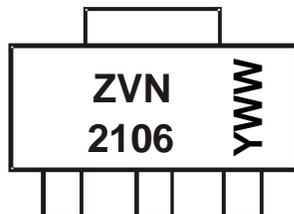
Equivalent Circuit

Ordering Information (Note 4)

Part Number	Package	Packing	
		Qty.	Carrier
ZVN2106GTA	SOT223 (Type DN)	1,000	Tape & Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



ZVN2106 = Product Type Marking Code
 YWW = Date Code Marking
 Y or \bar{Y} = Last Digit of Year (ex: 1 = 2021)
 WW or $\bar{W}\bar{W}$ = Week Code (01~53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	60	V
Gate-Source Voltage	V _{GSS}	±20	V
Continuous Drain Current	I _D	0.71	A
Pulsed Drain Current (Note 6)	I _{DM}	8	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

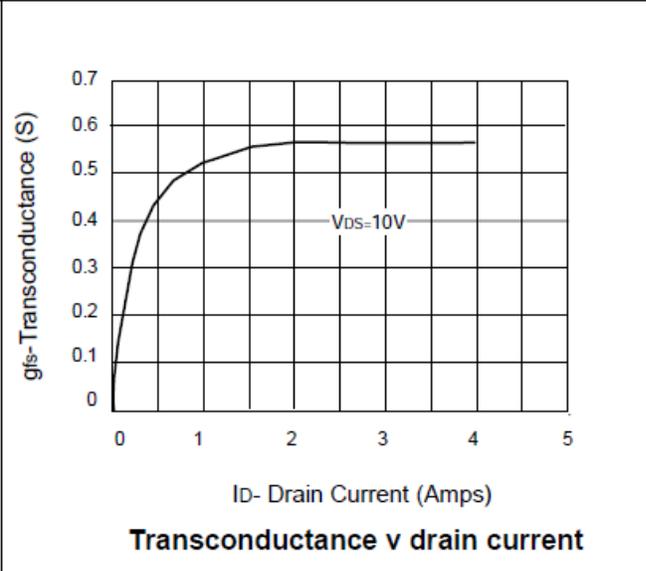
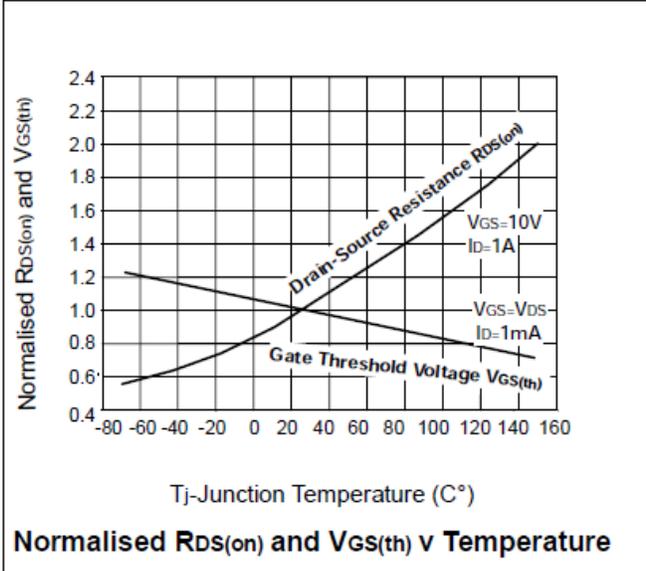
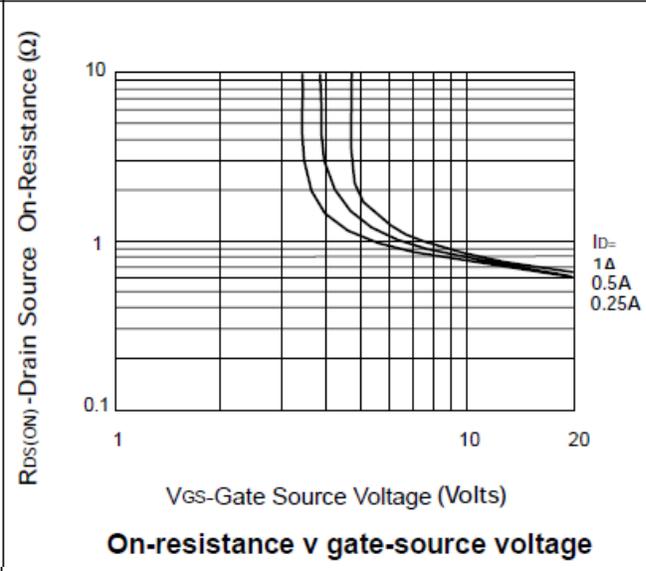
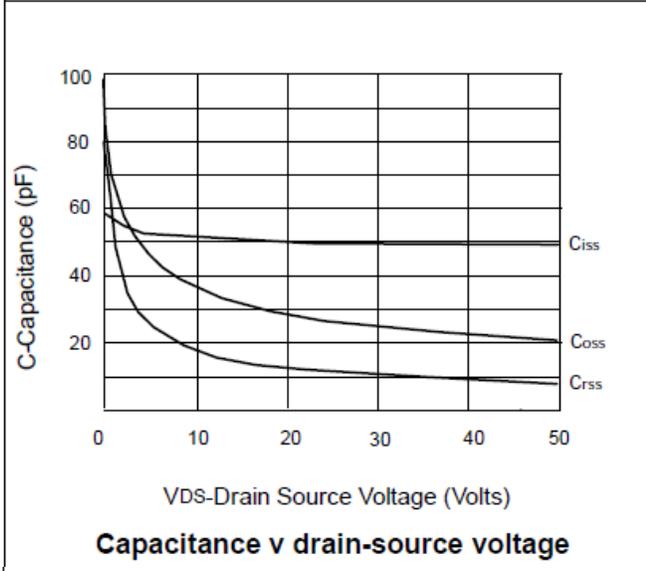
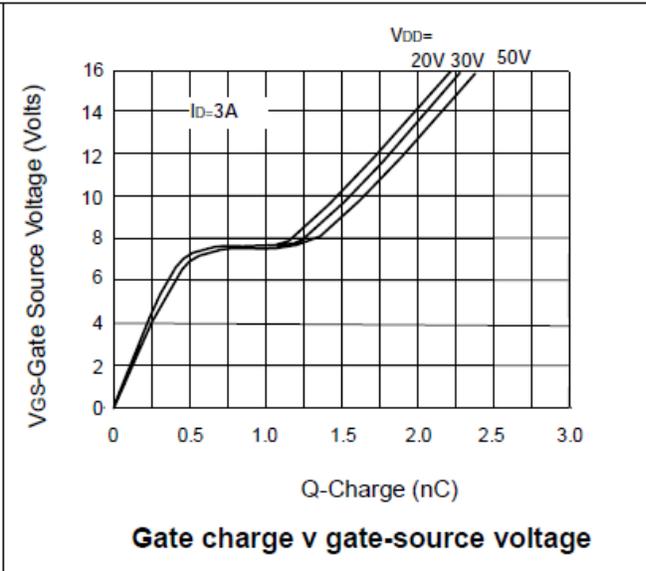
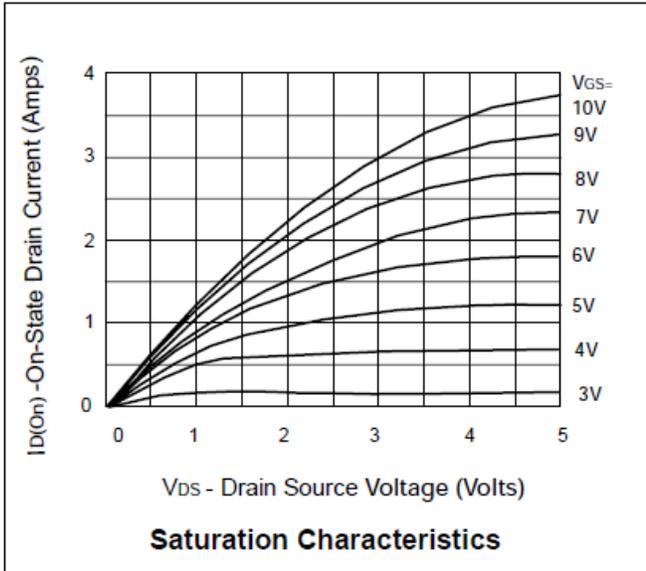
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	2	W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV _{DSS}	60	-	-	V	V _{GS} = 0V, I _D = 1mA
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	-	-	500 100	nA μA	V _{DS} = 60V, V _{GS} = 0V V _{DS} = 48V, V _{GS} = 0V, T _A = +125°C
Gate-Source Leakage	I _{GSS}	-	-	±20	nA	V _{GS} = ±20V, V _{DS} = 0V
On-State Drain Current	I _{D(ON)}	2	-	-	A	V _{GS} = 10V, V _{DS} = 18V
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(TH)}	0.8	-	2.4	V	V _{DS} = V _{GS} , I _D = 1mA
Static Drain-Source On-Resistance	R _{DS(ON)}	-	-	2	Ω	V _{GS} = 10V, I _D = 1.0A
Forward Transconductance	g _{fs}	0.3	-	-	S	V _{DS} = 18V, I _D = 1.0A
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	C _{iss}	-	-	75	pF	V _{DS} = 18V, V _{GS} = 0V, f = 1.0MHz
Output Capacitance	C _{oss}	-	-	45	pF	
Reverse Transfer Capacitance	C _{rss}	-	-	20	pF	
Turn-On Delay Time	t _{D(ON)}	-	-	7	ns	V _{DD} = 18V, I _D = 1A, V _{GEN} = 10V, R _{GS} = 50Ω
Turn-On Rise Time	t _R	-	-	8	ns	
Turn-Off Delay Time	t _{D(OFF)}	-	-	12	ns	
Turn-Off Fall Time	t _F	-	-	15	ns	

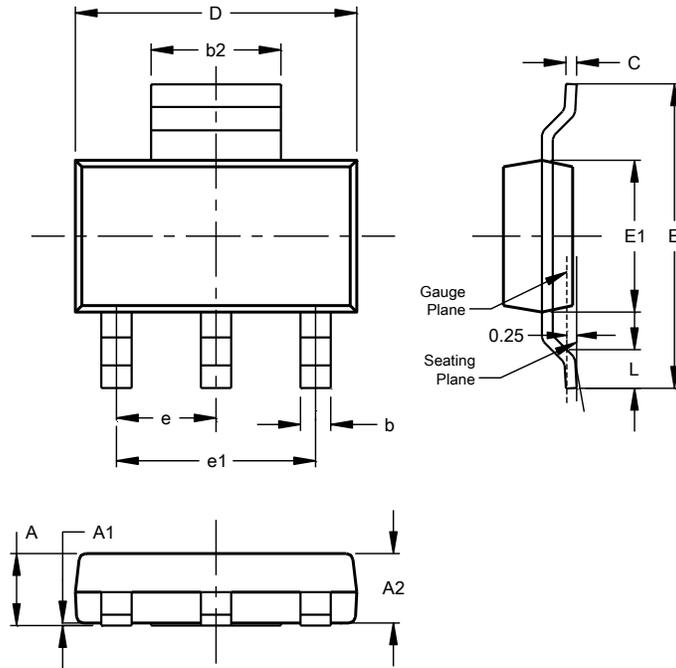
- Notes:
5. For a device mounted on 50mm x 50mm x 1.6mm FR-4 PCB with high coverage of single sided 2oz copper, in still air condition.
 6. Device mounted on minimum recommended pad layout test board, 10μs pulse duty cycle = 1%.
 7. Short duration pulse test used to minimize self-heating effect.
 8. Guaranteed by design. Not subject to production testing.

Typical Characteristics



Package Outline Dimensions

Please see <https://www.diodes.com/design/support/packaging/diodes-packaging/> for the latest version.

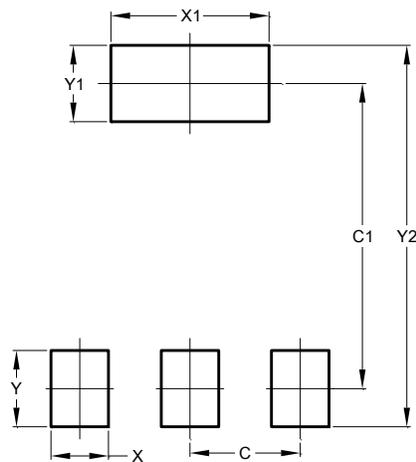


SOT223 (Type DN)			
Dim	Min	Max	Typ
A	--	1.70	--
A1	0.01	0.15	--
A2	1.50	1.68	1.60
b	0.60	0.80	0.70
b2	2.90	3.10	--
c	0.20	0.32	--
D	6.30	6.70	--
E	6.70	7.30	--
E1	3.30	3.70	--
e	--	--	2.30
e1	--	--	4.60
L	0.85	--	--
All Dimensions in mm			

Suggested Pad Layout

Please see <https://www.diodes.com/design/support/packaging/diodes-packaging/> for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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